

# An Integral Equation Scheme for Plasma based Thin Sheets

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**ELECTRICAL & COMPUTER  
ENGINEERING**

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- Motivation and Objective
- Background
- Theory and Methods
  - Subwavelength phenomena - Dispersion relations
  - Existence of plasmonic behavior - Sommerfeld Integral analysis
  - Surface Integral equation scheme
- Conclusions

# Motivation and Objective

- Plasmonics: subwavelength localization of electromagnetic (EM) fields
- Bridging the THz gap

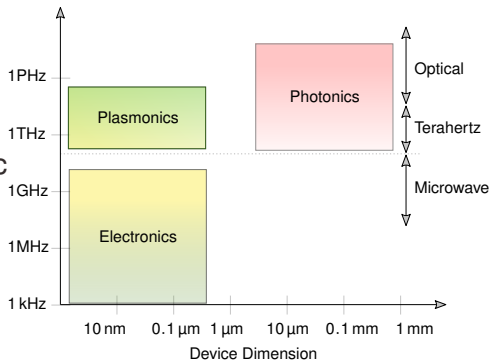


Figure: Communication Technologies at various frequencies

# Background

## Two-dimensional Electron Gas (2DEG)

- Semiconductor Heterostructure in high electron mobility transistor (HEMT)
- High concentration of free electrons  
( $\sim 1 \times 10^{11} - 1 \times 10^{14} \text{ cm}^{-2}$ )
- Very high Mobility  
( $\sim 1 \times 10^3 - 1 \times 10^6 \text{ cm}^2/\text{V/s}$ )
- Formation of Quantum Well
  - Two-dimensional confinement of electrons

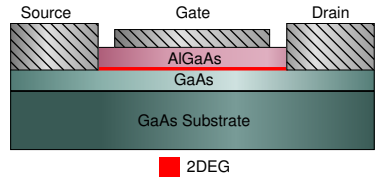


Figure: Typical GaAs/AlGaAs HEMT

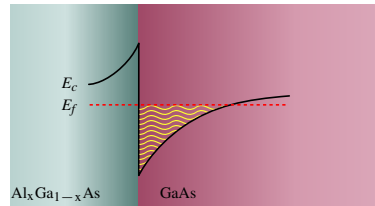
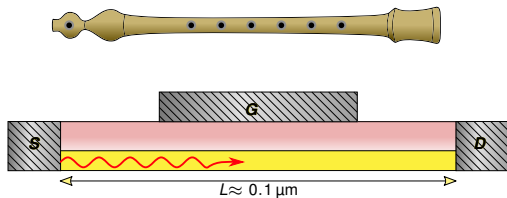


Figure: Band diagram of a GaAs/AlGaAs heterostructure

# Background

## 2DEG (contd.)

- Plasma waves in 2DEG
- Dyakonov-Shur instability
  - Voltage bias at source and drain terminals
  - Plasma resonance
  - THz emission
- Electronic Flute
  - Tunable resonance with gate voltage



$$\lambda = \frac{c}{f}$$

$$\Rightarrow 300 \mu\text{m}$$

# Theory and Methods

## Field Computation - Thin sheet

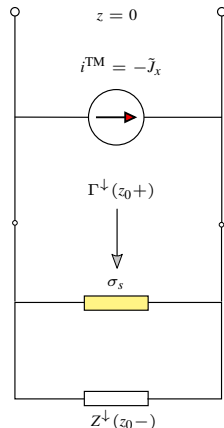
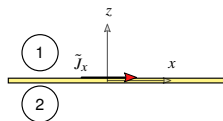
- Thin conductive sheet in free-space

$$Z^{\downarrow}(z_0^+) = \frac{Z_0}{1 + \sigma_s Z_0}$$

$$\Gamma^{\downarrow, \text{TE}} = \frac{k_{z1} - \omega \mu_1 \sigma_s}{k_{z1} + \omega \mu_1 \sigma_s}$$

$$\Gamma^{\downarrow, \text{TM}} = \frac{\omega \epsilon_1 - \sigma_s k_{z1}}{\omega \epsilon_1 + \sigma_s k_{z1}}$$

$$G_{zx}^A = \frac{j\mu}{2} \cos \phi \mathcal{S}_1 \left\{ \frac{\Gamma^{\downarrow, \text{TM}} - \Gamma^{\downarrow, \text{TE}}}{k_{\rho}} \right\}.$$



# Theory and Methods



## Thin Sheet Simulation

- Volume Integral formulation

$$\mathbf{A} = \frac{\mu}{4\pi} \int_V \mathbf{J}_v(\mathbf{r}') \frac{e^{-jk_1|\mathbf{r}-\mathbf{r}'|}}{|\mathbf{r}-\mathbf{r}'|} dv'$$

$$\mathbf{E}_1^{scat} = -\frac{j\omega}{k_1^2} (k_1^2 + \nabla\nabla\cdot) \mathbf{A}$$

$$\mathbf{J}_v = \frac{-jk_1}{Z_0} (\epsilon_2 - 1) \mathbf{E}_2$$

- Surface current  $J_s$   
approximated from  $J_v$

- Impedance (Leontovich)  
Boundary Condition

$$\mathbf{E}_{tan} = \eta Z_0 \hat{\mathbf{n}} \times \mathbf{H}$$

$$E^i = \eta Z_0 J_s(x') + \frac{\omega\mu}{4} \int_l J_s(x') H_0^{(2)}(k_2|x-x'|) dx'$$

# Theory and Methods

## Proposed Surface Integral Equation (SIE) scheme

- Surface Equivalence Theorem

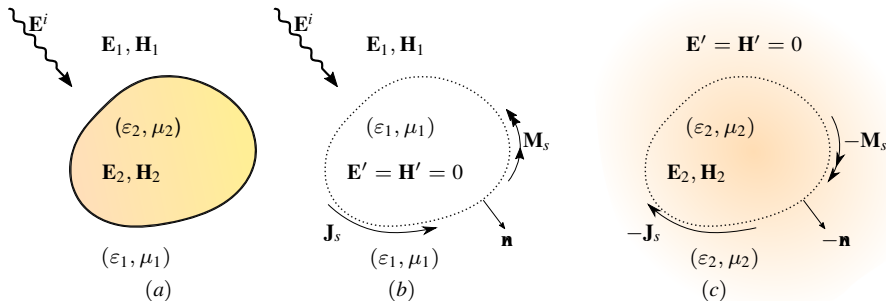


Figure: (a). Actual and its equivalent models for the (b) external and, (c) Internal region



# Proposed Scheme

## Surface Integral Equation

- Exterior Region

$$\begin{aligned}\mathbf{E}_1 &= \mathbf{E}_i + \mathbf{E}_1^{scat} \\ &= -\frac{\omega}{4k_1^2} (k_1^2 + \nabla \nabla \cdot) \int_C \mathbf{J}_s(\mathbf{p}') H_0^{(2)}(k_1 |\rho - \rho'|) d\mathbf{l}' \\ &\quad - \frac{1}{4\epsilon_j} \nabla \times \int_l \mathbf{M}_s(\rho') H_0^{(2)}(k_1 |\rho - \rho'|) d\mathbf{l}' + \mathbf{E}_i\end{aligned}$$

$$\begin{aligned}\mathbf{H}_1 &= \mathbf{H}_i + \mathbf{H}_1^{scat} \\ &= \frac{1}{4j} \nabla \times \int_l \mathbf{J}_s(\rho') H_0^{(2)}(k_1 |\rho - \rho'|) d\mathbf{l}' \\ &\quad - \frac{\omega}{4k_1^2} (k_1^2 + \nabla \nabla \cdot) \int_l \mathbf{M}_s(\rho') H_0^{(2)}(k_1 |\rho - \rho'|) d\mathbf{l}' + \mathbf{H}_i\end{aligned}$$

# Proposed Scheme

## Surface Integral Equation

- Interior Region

$$\begin{aligned}\mathbf{E}_2 &= \mathbf{E}_2^{scat} \\ &= -\frac{\omega}{4k_2^2} (k_2^2 + \nabla \nabla \cdot) \int_C (-\mathbf{J}_s(\mathbf{p}')) H_0^{(2)}(k_2|\rho - \rho'|) d\mathbf{l}' \\ &\quad - \frac{1}{4j} \nabla \times \int_l (-\mathbf{M}_s(\rho')) H_0^{(2)}(k_2|\rho - \rho'|) d\mathbf{l}'\end{aligned}$$

$$\begin{aligned}\mathbf{H}_2 &= \mathbf{H}_1^{scat} \\ &= \frac{1}{4j} \nabla \times \int_l (-\mathbf{J}_s(\rho')) H_0^{(2)}(k_2|\rho - \rho'|) d\mathbf{l}' \\ &\quad - \frac{\omega}{4k_2^2} (k_2^2 + \nabla \nabla \cdot) \int_l (-\mathbf{M}_s(\rho')) H_0^{(2)}(k_2|\rho - \rho'|) d\mathbf{l}'\end{aligned}$$

# Theory and Methods



$TM_z$  SIE for Thin Flat Sheet

$$\hat{\mathbf{n}} \times (\mathbf{E}_1 - \mathbf{E}_2) = \mathbf{0}$$

$$E_i = \frac{\omega}{4} \int_L J_z(x') \left[ H_0^{(2)}(k_1|x - x'|) + H_0^{(2)}(k_2|x - x'|) \right] dx'$$

$$\hat{\mathbf{n}} \times (\mathbf{H}_1 - \mathbf{H}_2) = \mathbf{0}$$

$$H_i^{tan} = \frac{-j\omega}{2} \int_L M_x(x') \left[ \varepsilon_1 H_0^{(2)}(k_1|x - x'|) + \varepsilon_1 H_2^{(2)}(k_1|x - x'|) \right. \\ \left. + \varepsilon_2 H_0^{(2)}(k_2|x - x'|) + \varepsilon_2 H_2^{(2)}(k_2|x - x'|) \right] dx'$$

## Method of moments

- Integral equations to system of linear equations

$$\begin{bmatrix} Z_{mn} & 0 \\ 0 & Y_{mn} \end{bmatrix} \begin{bmatrix} J_n \\ M_n \end{bmatrix} = \begin{bmatrix} E_m^i \\ H_m^i \end{bmatrix}$$

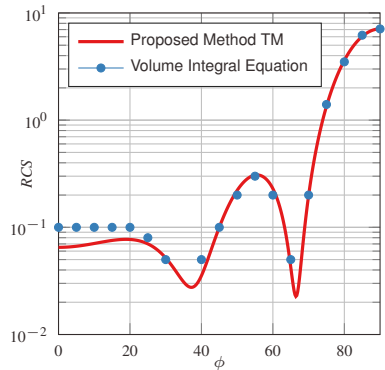
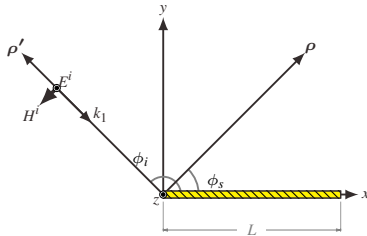
- Pulse basis functions and Point matching used
- Far-field

$$RCS(\phi) \simeq \int_0^L [J_z(x')\eta_1 + M_x(x') \sin(\phi_i)] e^{jk_1 x' \cos(\phi_i)} dx'$$

# Results

## Thin Sheet Simulation ( $TM_z$ )

- $TM_z$  polarization
- Dielectric Rod of length  $2.5 \lambda$
- $\epsilon = 4, \mu = 1$

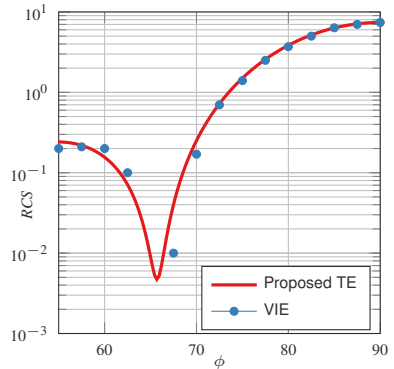
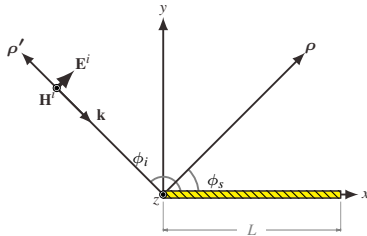


- Thickness of  $.05\lambda$  assumed in Volume Integral equation model

# Results

## Thin Sheet Simulation ( $TE_z$ )

- $TE_z$  polarization
- Dielectric Rod of length  $2.5 \lambda$
- $\epsilon = 4, \mu = 1$

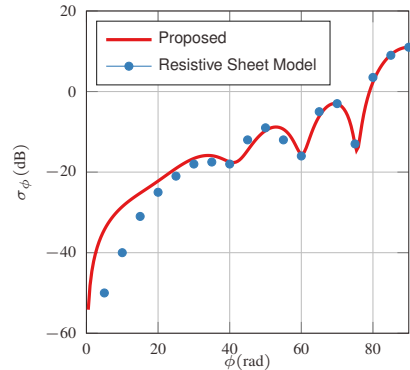
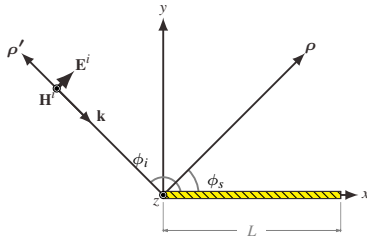


- Thickness of  $.05\lambda$  assumed in Volume Integral equation model

# Results

## Thin Sheet Simulation ( $TE_z$ )

- $TE_z$  polarization
- Dielectric Rod of length  $2\lambda$
- $\epsilon = 4$ ,  $\mu = 1$



- Thickness of  $.628/k_1$  assumed in resistive model

# Summary



## Two-dimensional plasmonic devices

- Subwavelength wave phenomena at optical and terahertz frequencies
- Realization of terahertz sources and sensors
- 2D nature of waves permits subwavelength confinement
- Plasmonic activity
- Nanoscale imaging using terahertz plasma waves



Thank you!

Questions?